## NSN 5962-01-345-1146

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View Online at https://aerobasegroup.com/nsn/5962-01-345-1146
Overall Length:
Between 0.342 inches and 0.358 inches
Overall Height:
Between 0.060 inches and 0.100 inches
Overall Width:
Between 0.342 inches and 0.358 inches
Body Length:
Between 0.342 inches and 0.358 inches
Body Width:
Between 0.342 inches and 0.358 inches
Body Height:
Between 0.060 inches and 0.100 inches
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and electrostatic sensitive and 3-state output and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Current Rating Per Characteristic:
180.00 milliamperes supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
25.00 nanoseconds delay
Memory Device Type:
Programmable
Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Yes - demil/mli

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